

REJ03F0164-0200 Rev.2.00 Jun 14, 2006

# Description

The M52334FP is IF signal-processing IC for VCRs and TVs. It enables the PLL detection system despite size as small as that of conventional quasi-synchronous VIF/SIF detector, IF/RF AGC, SIF limiter and FM detector.

# Features

- Video detection output is  $2 V_{P-P}$ . It has built-in EQ AMP.
- The package is a 20-pin flat package, suitable for space saving.
- The video detector uses PLL for full synchronous detection circuit. It produces excellent characteristics of DG, DP, 920 kHz beat, and cross color.
- Dynamic AGC realizes high-speed response with only single filter.
- Video IF and sound IF signal processing are separated from each other. VCO output is used to obtain intercarrier.
- As AFT output voltage uses the APC output voltage, VCO coil is not used.
- Audio FM demodulation uses PLL system, so it has wide frequency range with no external parts and no adjustment.
- This IC corresponds to only inter of NTSC system.

# Application

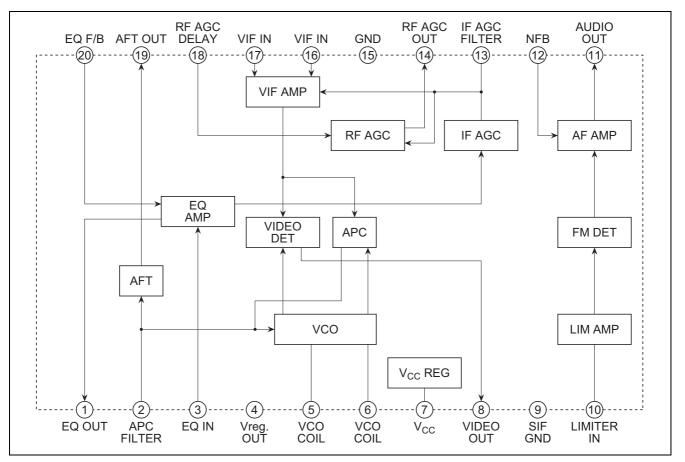
TV sets, VCR tuners

# **Recommended Operating Condition**

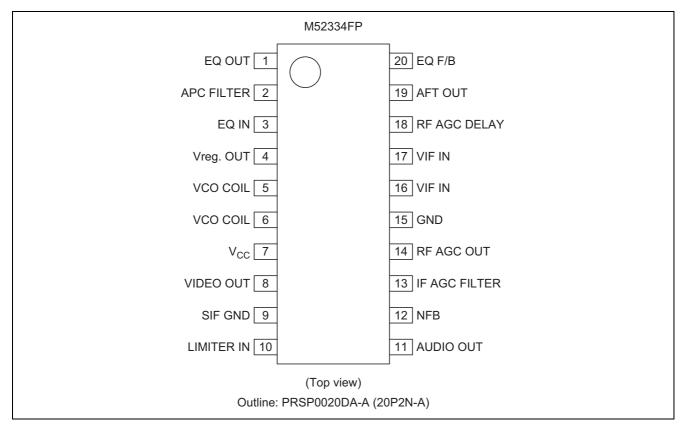
- In case of V<sub>CC</sub> and Vreg. OUT short
  - Supply voltage range: 4.75 to 5.25 V
  - Recommended supply voltage: 5.0 V
- Incase of Vreg. OUT open
  - Supply voltage range: 8.5 to 12.5 V



# **Block Diagram**



## **Pin Arrangement**







# Absolute Maximum Ratings

				$(Ta = 25^{\circ}C, unless otherwise noted)$
ltem	Symbol	Ratings	Unit	Condition
Supply voltage1	V <sub>cc</sub>	13.2	V	V <sub>CC</sub> and Vreg. out is not connected to each other.
Supply voltage Vreg. OUT	Vreg. OUT	6.0	V	$V_{\text{CC}}$ and Vreg. out is not connected to each other.
Power dissipation	Pd	1225	mW	
Operating temperature	Topr	-20 to +85	°C	
Storage temperature	Tstg	-40 to +150	°C	
Surge voltage resistance	Surge	200	V	Surge protection capacitance 200 pF resistance 0

# **Electrical Characteristics**

						(V <sub>CC</sub>	=9 V, 1	$a = 25^{\circ}$	C, unless o	otherwise noted.)
						Limits				Test Conditions
Item	Symbol	Test Circuit	Test Point	Input Point	Input SG	Min.	Тур.	Max.	Unit	Switches set to position 1 unless otherwise indicated
VIF section				1	1					
Circuit current1 $V_{CC} = 5V$	I <sub>CC1</sub>	1	A	_	_	33	40.5	47	mA	$V_{CC} = 5V$ SW4 = 2, SW7 = 2
Circuit current2 $V_{CC} = 12V$	I <sub>CC2</sub>	1	A	—		31	40.5	49	mA	V <sub>CC</sub> = 12V SW7 = 2
Vreg voltage2	V <sub>CC2</sub>	1	TP4	—	_	4.7	5.00	5.3	V	$V_{CC} = 12V$
Video output DC voltage1	V1	1	TP1A	—	_	3.45	3.9	4.35	V	SW13 = 2 V13 = 0V
Video output voltage8	Vo det8	1	TP8	VIF IN	SG1	0.85	1.1	1.35	$V_{P-P}$	
Video output voltage1	Vo det	1	TP1A	VIF IN	SG1	1.85	2.2	2.55	$V_{P-P}$	
Video S/N	Video S/N	1	TP1B	VIF IN	SG2	51	56	—	dB	SW1 = 2
Video band width	BW	1	TP1A	VIF IN	SG3	5.0	7.0	—	MHz	SW13 = 2 V13 = variable
Input sensitivity	VIN MIN	1	TP1A	VIF IN	SG4		48	52	dBμ	
Maximum allowable input	VIN MAX	1	TP1A	VIF IN	SG5	101	105		dBμ	
AGC control range input	GR	—	—	—		50	57		dB	
IF AGD voltage	V13	1	TP13	VIF IN	SG6	2.85	3.15	3.45	V	
Maximum IF AGC voltage	V13H	1	TP13		_	4.0	4.4	—	V	
Maximum IF AGC voltage	V13L	1	TP13	VIF IN	SG7	2.2	2.4	2.6	V	
Maximum RF AGC voltage	V14H	1	TP14	VIF IN	SG2	8.0	8.7	—	V	SW13 = 2 V13 = 4V
Minimum RF AGC voltage	V14L	1	TP14	VIF IN	SG2		0.1	0.5	V	SW13 = 2 V13 = 1V



 $(V_{CC} = 9 V, Ta = 25^{\circ}C, unless otherwise noted.)$ 

							Limits			Test Conditions
ltem	Symbol	Test Circuit	Test Point	Input Point	Input SG	Min.	Тур.	Max.	Unit	Switches set to position 1 unless otherwise indicated
RF AGC operation	V14	1	TP14	VIF IN	SG8	86	89	92	dBμ	
voltage										
Capture range U	CL-U	1	TP1A	VIF IN	SG9	0.8	1.3		MHz	
Capture range L	CL-L	1	TP1A	VIF IN	SG9	1.4	2.0		MHz	
Capture range T	CL-T	1	_	_	_	2.5	3.3		MHz	
AFT sensitivity		1	TP19	VIF IN	SG10	20	30	70	mV/kHz	
AFT maximum voltage	V19H	1	TP19	VIF IN	SG10	7.7	8.2	—	V	
AFT minimum voltage	V19L	1	TP19	VIF IN	SG10	—	0.7	1.2	V	
AFT defeat 1	AFT def1	1	TP19	VIF IN	—	4.2	4.5	4.8	V	
Inter modulation	IM	1	ТРЗА	VIF IN	SG11	35	42	—	dB	SW13 = 2 V13 = variable
Differential gain	DG	1	TP3A	VIF IN	SG12	—	2	5	%	
Differential phase	DP	1	TP3A	VIF IN	SG12	—	2	5	deg	
Sync. tip level	V3 SYNC	1	ТРЗА	VIF IN	SG2	1.0	1.4	1.8	V	
VIF input resister	RINV	2	TP17				1.2		kΩ	
VIF input capacitance	CINV	2	TP17	_	—	—	5	—	pF	
SIF section							•	•		
AF output DC voltage	V1	1	TP11	—	—	3.5	4.4	5.3	V	
AF output	VoAF	1	TP11	SIF IN	SG16	565	790	1125	mVrms	
AF output distortion	THD AF	1	TP11	SIF IN	SG16	—	0.4	0.9	%	
Limiting sensitivity	LIM	1	TP11	SIF IN	SG17	_	42	55	dBμ	
AM rejection	AMR	1	TP11	SIF IN	SG18	55	65	—	dB	
AF S/N	AF S/N	1	TP11	SIF IN	SG19	55	65	—	dB	

# **Electrical Characteristics Test Method**

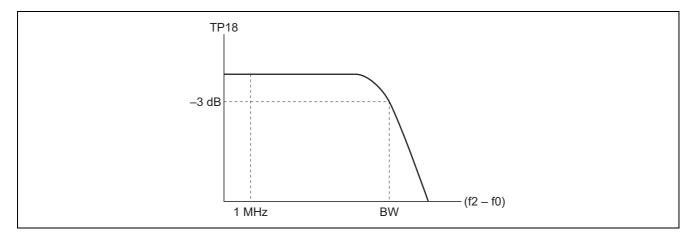
### Video S/N

Input SG2 into VIF IN and measure the video out (Pin 3) noise in r.m.s at TP3-B through a 5 MHz (-3 dB) L.P.F.

$$S/N = 20 \log \left( \frac{0.7 \bullet Vo det}{NOISE} \right) \quad (dB)$$

#### **BW Video Band Width**

- 1. Measure the 1 MHz component level of EQ output TP3A with a spectrum analyzer when SG3 (f2 = 44.75 MHz) is input into VIF IN. At that time, measure the voltage at TP13 with SW13, set to position 2, and then fix V13 at that voltage.
- 2. Reduce f2 and measure the value of (f2 f0) when the (f2 f0) component level reaches -3 dB from the 1 MHz component level as shown below.



#### **VIN MIN Input Sensitivity**

Input SG4 (Vi = 90 dB $\mu$ ) into VIF IN, and then gradually reduce Vi and measure the input level when the 20 kHz component of EQ output TP3A reaches -3 dB from Vo det level.

### **VIN MAX Maximum Allowable Input**

- 1. Input SG5 (Vi = 90 dB $\mu$ ) into VIF IN, and measure the level of the 20 kHz components of EQ output.
- 2. Gradually increase the Vi of SG and measure the input level when the output reaches -3 dB.

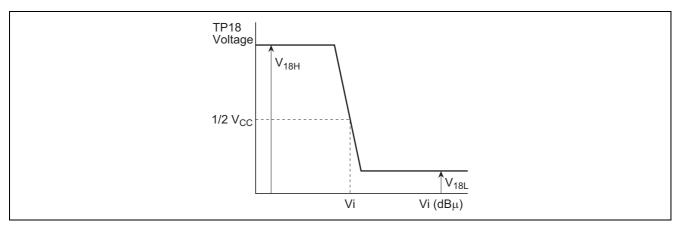
### **GR AGC Control Range**

GR = VIN MAX - VIN MIN (dB)



## V18 RF AGC Operating Voltage

Input SG8 into VIF IN, and gradually reduce Vi and then measure the input level when RF AGC output TP14 reaches  $1/2 V_{CC}$ , as shown below.



### **CL-U Capture Range**

- 1. Increase the frequency of SG9 until the VCO is out of locked-oscillation.
- 2. Decrease the frequency of SG9 and measure the frequency fU when the VCO locks. CL-U = fU - 45.75 (MHz)

### **CL-L Capture Range**

- 1. Decrease the frequency of SG9 until the VCO is out of locked-oscillation.
- 2. Increase the frequency of SG9 and measure the frequency fL when the VCO locks. CL-L = 45.75 - fL (MHz)

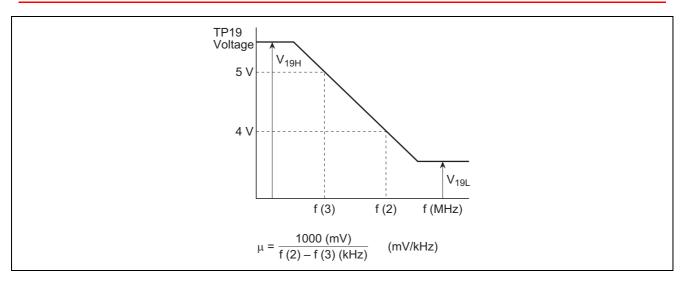
## **CL-T Capture Range**

CL-T = CL-U + CL-L (MHz)

### $\mu$ AFT Sensitivity, V<sub>19H</sub> AFT Maximum Voltage, V<sub>19L</sub> AFT Minimum Voltage

- 1. Input SG10 into VIF IN, and set the frequency of SG 10 so that the voltage of AFT output TP19 is 5 V. This frequency is named f (3).
- 2. Set the frequency of SG10 so that the AFT output voltage is 4 V. This frequency is named f (2).
- 3. In the graph, maximum and minimum DC voltage are  $V_{19H}$  and  $V_{19L}$ , respectively.





### **IM Intermodulation**

- 1. Input SG11 into VIF IN, and measure EQ output TP3A with an oscilloscope.
- 2. Adjust AGC filter voltage V13 so that the minimum DC level of the output waveform is 1.0 V.
- 3. At this time, measure, TP3A with a spectrum analyzer. The intermoduration is defined as a difference between 0.92 MHz and 3.58 MHz frequency components.

#### LIM Limiting Sensitivity

- 1. Input SG17 (Vi = 90 dB $\mu$ ) into SIF input, and measure the 400 Hz component level of AF output TP11.
- 2. Lower the input level of SG17, and measure the level of SG17 when the VoAF level reaches -3 dB.

#### **AMR AM Rejection**

- 1. Input SG18 into SIF input, and measure the output level of AF output TP11. This level is named VAM.
- 2. AMR is;

$$AMR = 20 \log \left( \frac{VoAF (mVrms)}{VAM (mVrms)} \right) (dB)$$

## AF S/N

- 1. Input SG19 into SIF input, and measure the output noise level of AF output TP11. This level is named VN.
- 2. S/N is;

$$S/N = 20 \log \left( \frac{VoAF (mVrms)}{VN (mVrms)} \right) (dB)$$



# The Note in The System Setup

M52234FP has 2 power supply pins of  $V_{CC}$  (pin 7) and Vreg. OUT (pin 4). Pin 7 is for AFT output, RF AGC output circuits and 5 V regulated power supply circuit and pin 4 is for the other circuit blocks. In case M52334FP is used together with other ICs like VIF operating at more than 5 V, the same supply voltage as that of connected ICs is applied to  $V_{CC}$  and Vreg. OUT is opened. The other circuit blocks, connected to Verg. OUT are powered by internal 5 V regulated power supply.

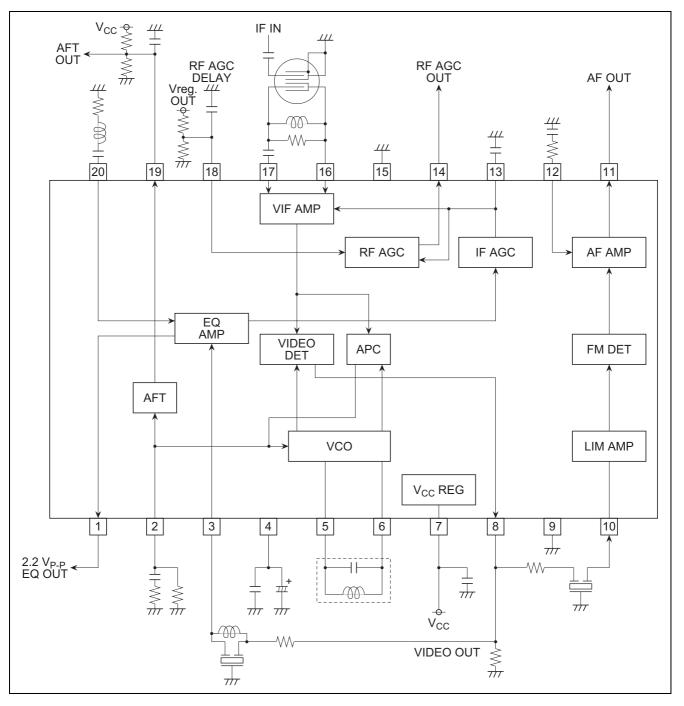
In case the connecting ICs are operated at 5 V, 5 V is supplied to both V<sub>CC</sub> and Vreg. OUT.

SG No.	Signals (50 Ω Termination)
1	$f_0 = 45.75 \text{ MHz}$ AM 20 kHz 77.8% 90 dB $\mu$
2	$f_0 = 45.75 \text{ MHz} 90 \text{ dB}\mu \text{ CW}$
3	$f_1 = 45.75 \text{ MHz} 90 \text{ dB}\mu \text{ CW}$ (Mixed signal)
	$f_2 =$ Frequency variable 70 dB $\mu$ CW (Mixed signal)
4	$f_0 = 45.75 \text{ MHz}$ AM 20 kHz 77.8% level variable
5	$f_0 = 45.75 \text{ MHz}$ AM 20 kHz 14.0% level variable
6	$f_0 = 45.75 \text{ MHz} 80 \text{ dB}\mu \text{ CW}$
7	$f_0 = 45.75 \text{ MHz} 110 \text{ dB}\mu \text{ CW}$
8	$f_0 = 45.75 \text{ MHz} \text{ CW}$ level variable
9	$f_0 = Variable AM 20 \text{ kHz} 77.8\% 90 \text{dB}\mu$
10	$f_0 = Variable 90 dB\mu CW$
11	$f_1 = 45.75 \text{ MHz} 90 \text{ dB}\mu \text{ CW}$ (Mixed signal)
	$f_2 = 42.17 \text{ MHz} 80 \text{ dB}\mu \text{ CW}$ (Mixed signal)
	$f_3 = 41.25 \text{ MHz} 80 \text{ dB}\mu \text{ CW}$ (Mixed signal)
12	$f_0 = 45.75 \text{ MHz} 87.5\%$
	TV modulation ten-step waveform
	Sync tip level 90 dBµ
13	$f_1 = 41.25 \text{ MHz} \ 103 \text{ dB}\mu \ \text{CW}$
14	$f_1 = 41.25 \text{ MHz} 70 \text{ dB}\mu \text{ CW}$
15	$f_1 = 45.75 \text{ MHz} 90 \text{ dB}\mu \text{ CW}$ (Mixed signal)
	$f_2 = 41.25 \text{ MHz} 70 \text{ dB}\mu \text{ CW}$ (Mixed signal)
16	$f_0=4.5~\text{MHz}~90~\text{dB}\mu~\text{FM}~400~\text{Hz}\pm25~\text{kHz}~\text{dev}$
17	$f_0 = 4.5 \; \text{MHz} \; \; \text{FM} \; 400 \; \text{Hz} \pm 25 \; \text{kHz}$ dev level variable
18	$f_0 = 4.5 \text{ MHz} 90 \text{ dB}\mu \text{ AM400Hz} 30\%$
19	$f_0 = 4.5 \text{ MHz} 90 \text{ dB}\mu \text{ CW}$

# Input Signal

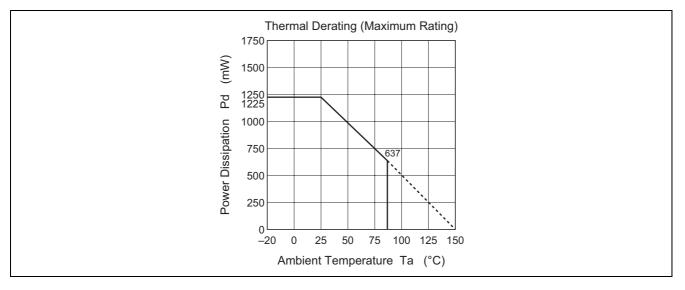


# **Test Circuit**



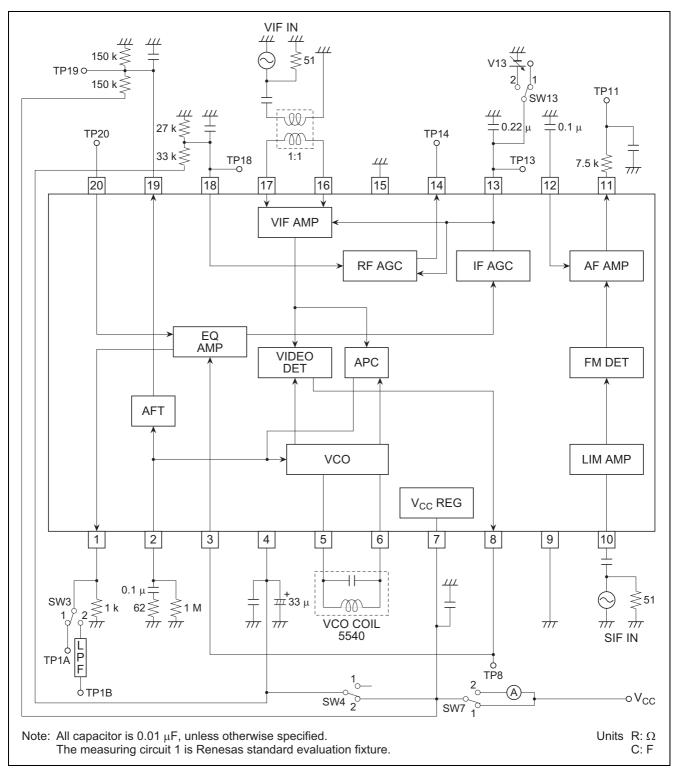


# **Typical Characteristics**



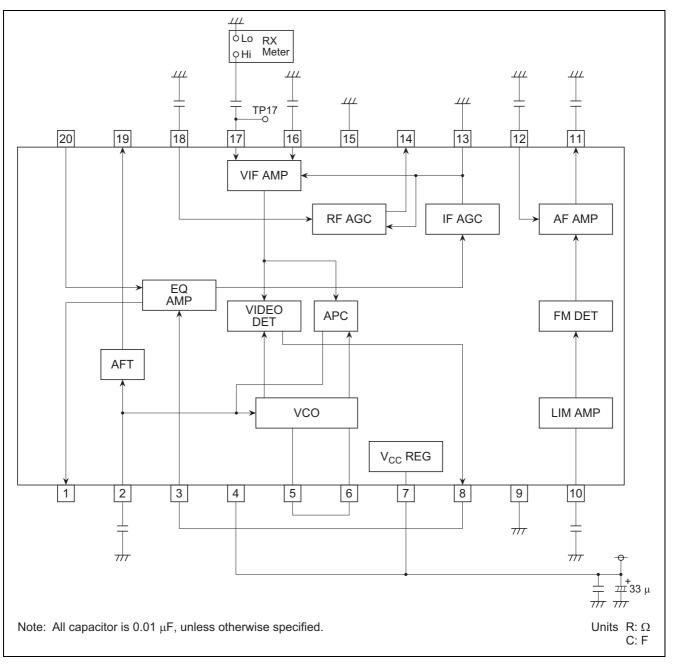


# **Application Example 1**



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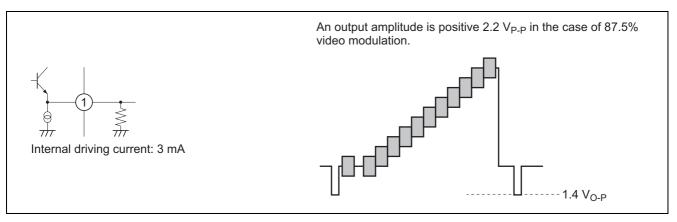
# **Application Example 2**



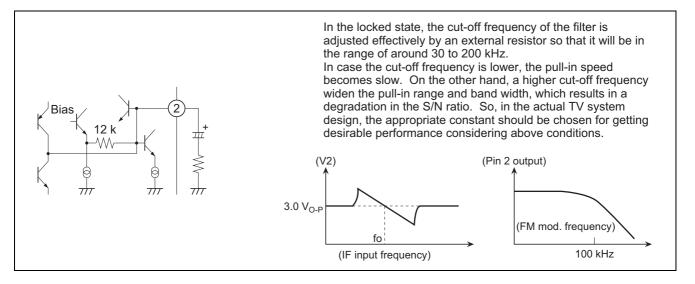


# **Pin Description**

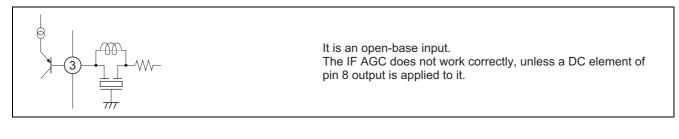
### Pin 1 (EQ OUT)



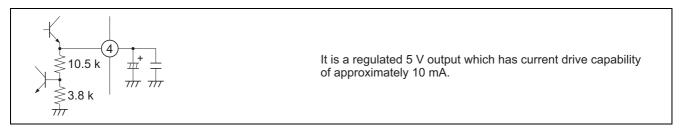
## Pin 2 (APC FILTER)



### Pin 3 (EQ IN)

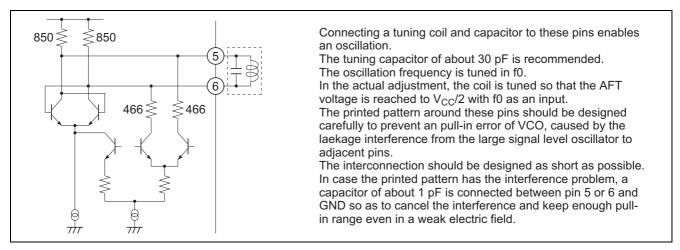


## Pin 4 (Vreg. OUT)

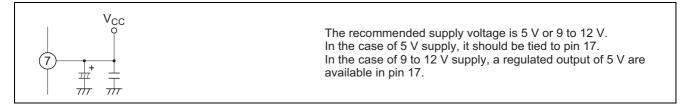




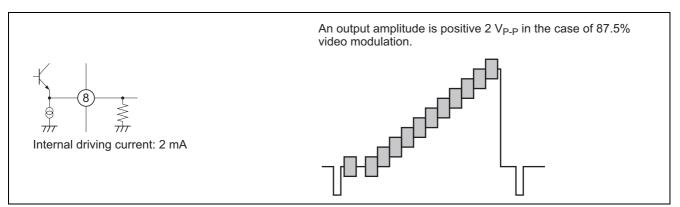
# Pin 5, Pin 6 (VCO COIL)



Pin 7 (V<sub>cc</sub>)



### Pin 8 (VIDEO OUT)

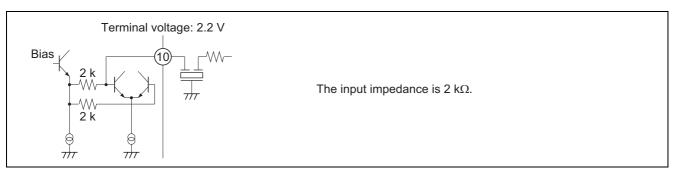


#### Pin 9 (SIF GND)

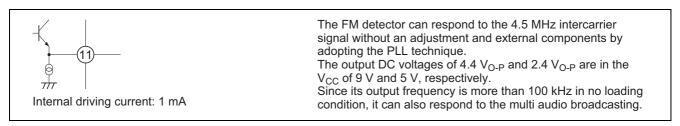




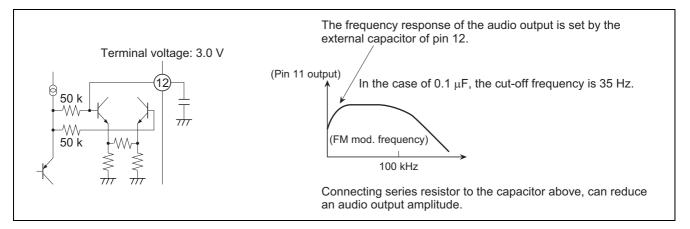
## Pin 10 (LIMITER IN)



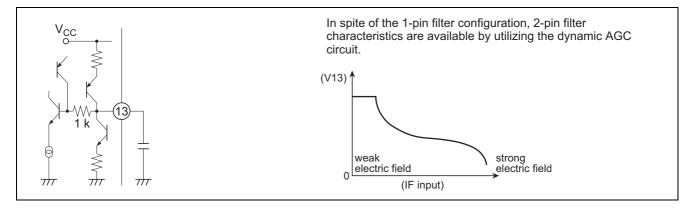
### Pin 11 (AUDIO OUT)



### Pin 12 (NFB)

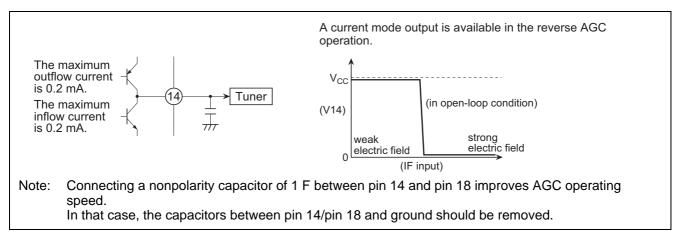


#### Pin 13 (IF AGC FILTER)





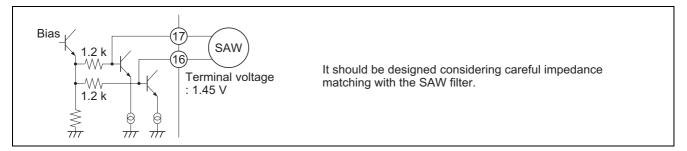
# Pin 14 (RF AGC OUT)



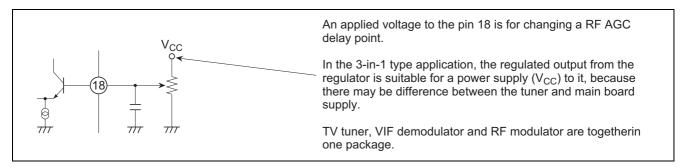
### Pin 15 (GND)



## Pin 16, Pin 17 (VIF IN)

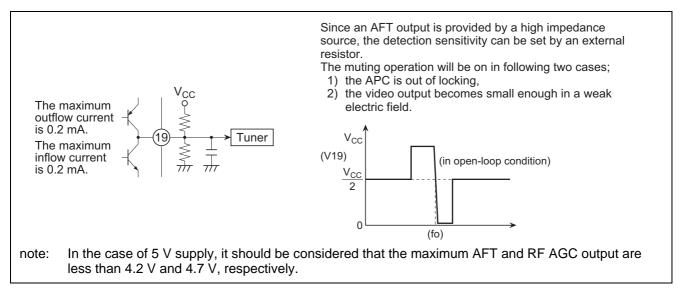


### Pin 18 (RF AGC DELAY)

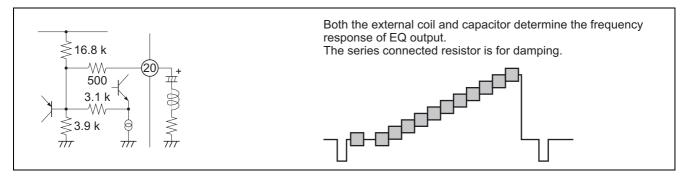




# Pin 19 (AFT OUT)

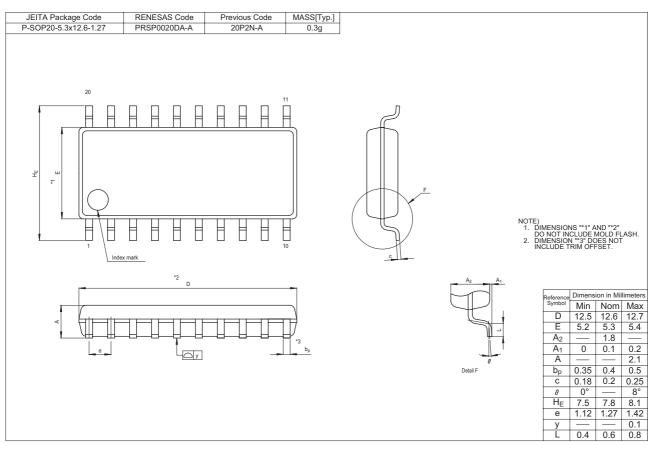


### Pin 20 (EQ F/B)





# **Package Dimensions**





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